

Seat No.: \_\_\_\_\_

Enrolment No. \_\_\_\_\_

# **GUJARAT TECHNOLOGICAL UNIVERSITY**

**DIPLOMA ENGG.- III<sup>rd</sup> SEMESTER-EXAMINATION – MAY/JUNE- 2012**

## **Subject code: 330902**

Date: 28/05/2012

## **Subject Name: Basic Electronics**

**Time: 02:30 pm – 05:00 pm**

**Total Marks: 70**

## Instructions:

1. Attempt all questions.
  2. Make suitable assumptions wherever necessary.
  3. Figures to the right indicate full marks.
  4. English version is considered to be Authentic

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|------------|---|-----------|
| <b>Q.1</b> | (a) Explain operation of CRT with necessary diagram.<br>(b) Discuss Intrinsic and Extrinsic semiconductors with atomic structure & energy band diagram.   | <b>07</b> |
| <b>Q.2</b> | (a) Explain working operation of semiconductor Diode with forward bias & reverse bias circuits and I-V characteristics.<br>(b) Draw symbol, construction and characteristics curves of following devices:<br>(i) Varactor diode.<br>(ii) Zener diode. | <b>07</b> |

OR

- (b) Draw symbol, construction and characteristics curves of following devices: 07

  - (i) TRIAC.
  - (ii) DIAC.

- Q.3** (a) Explain construction and basic operation of NPN transistor. **07**  
(b) Define  $\alpha$  and  $\beta$  of a transistor and derive relation between them. **07**

OR

- Q.3** (a) Explain transistor as an amplifier with CE configuration. **07**  
(b) Define H- parameters of transistor. **07**

- Q.4** (a) Compare LED with semiconductor LASER diode. **07**  
 (b) Compare CE, CC and CB transistor amplifiers. **07**

OR

- Q. 4** (a) Explain construction and working operation of the following devices. **14**

- (i) UJT.
  - (ii) SCR

- Q.5** (a) Explain construction and working operation of the following devices. **14**



OR

- Q.5** (a) Draw and explain application circuits of the following: **14**  
(i) UJT                      (ii) TRIAC

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